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## N 27 2003 INTHE UNITED STATES PATENT & TRADEMARK OFFICE

INTE APRIME ATION OF

SHUSUKE KAYA, ET AL.

: EXAMINER: JACKSON, C.

SERIAL NO: 09/662,704

FILED: SEPTEMBER 15, 2000

: GROUP ART UNIT: 2828

FOR: SEMICONDUCTOR LASER

**DEVICE** 

## **AMENDMENT**

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

Responsive to the Official Action mailed February 27, 2003, please amend the aboveidentified patent application as follows:

## IN THE CLAIMS

Please amend Claims 1, 9 and 18 as shown in clean form below:<sup>1</sup>

1. (Amended) A semiconductor laser device comprising

a semiconductor multi-layer film formed by laminating optical confinement layers and active layers so as to dispose each of said active layers between said optical confinement layers;

a high reflection film coated on a first end of the multi-layer film perpendicular to junction planes of the individual layers in said semiconductor multi-layer film; and

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<sup>&</sup>lt;sup>1</sup> A marked-up copy of the claims is attached hereto.